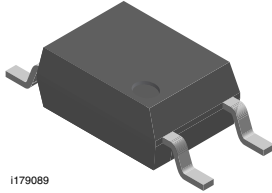
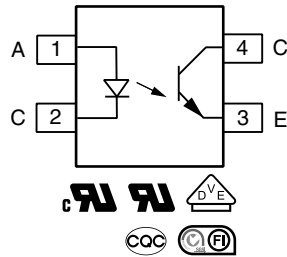


Low Input Current, Phototransistor Output, SOP-4, Mini-Flat Package



I179089



FEATURES

- Operating temperature from - 55 °C to + 110 °C
- SOP-4 mini-flat package
- Isolation test voltage, 3750 V_{RMS}
- Low saturation voltage
- Fast switching times
- Low coupling capacitance
- End-stackable, 0.100" (2.54 mm) spacing
- CTR range 40 % to 600 %, I_F = 5 mA
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



DESCRIPTION

The 110 °C rated VOM617A has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4 pin 100 mil lead pitch miniflat package. It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

These coupling devices are designed for signal transmission between two electrically separated circuits.

AGENCY APPROVALS

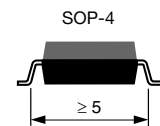
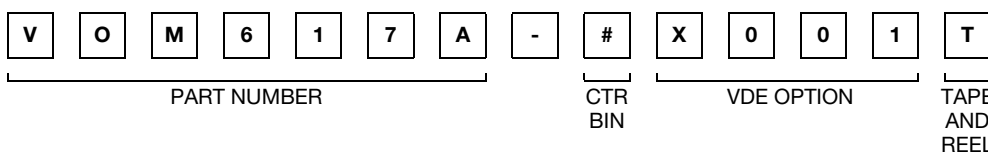
(All parts are certified under base model VOM617A)

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60065 and EN 60950-1
- CQC GB8898-2011, GB4943.1-2001

APPLICATIONS

- PLCs
- Telecommunication
- Lighting control system
- Solar inverters
- AC drives

ORDERING INFORMATION



AGENCY CERTIFIED/ PACKAGE	CTR (%)							
	5 mA							
UL, cUL, FIMKO, CQC	50 to 600	63 to 125	100 to 200	160 to 320	250 to 500	80 to 160	130 to 260	200 to 400
SOP-4, mini-flat	VOM617AT	VOM617A-2T	VOM617A-3T	VOM617A-4T	VOM617A-6T	VOM617A-7T	VOM617A-8T	VOM617A-9T
VDE, UL, cUL, FIMKO, CQC	50 to 600	63 to 125	100 to 200	160 to 320	250 to 500	80 to 160	130 to 260	200 to 400
SOP-4, mini-flat	VOM617A-X001T	VOM617A-2X001T	VOM617A-3X001T	VOM617A-4X001T	VOM617A-6X001T	VOM617A-7X001T	VOM617A-8X001T	VOM617A-9X001T

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
DC forward current		I_F	60	mA
Reverse voltage		V_R	6	V
Power dissipation		P_{diss}	70	mW
Surge forward current	$t_p \leq 10\text{ }\mu\text{s}$	I_{FSM}	2.5	A
OUTPUT				
Collector emitter voltage		V_{CEO}	80	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
	$t_p \leq 1\text{ ms}$		100	mA
Power dissipation		P_{diss}	150	mW
COUPLER				
Isolation test voltage between emitter and detector	$t = 1\text{ min}$	V_{ISO}	3750	V_{RMS}
Total power dissipation		P_{tot}	170	mW
Operating temperature range		T_{amb}	- 55 to + 110	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$
Junction temperature		T_j	125	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾		T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ See "Assembly Instructions" for surface mounted devices (www.vishay.com/doc?80054).

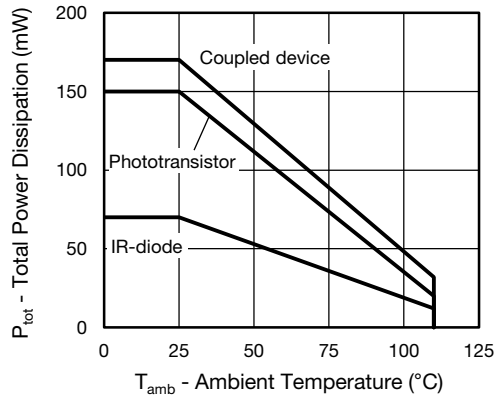


Fig. 1 - Total Power Dissipation vs. Ambient Temperature



ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 5\text{ mA}$	V_F		1.1	1.6	V
Reverse current	$V_R = 6\text{ V}$	I_R		0.01	10	μA
Capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_j		9		pF
OUTPUT						
Collector emitter leakage current	$V_{CE} = 20\text{ V}$	I_{CEO}		0.3	100	nA
Collector emitter breakdown voltage	$I_C = 100\text{ }\mu\text{A}$	BV_{CEO}	80			V
Emitter collector breakdown voltage	$I_E = 10\text{ }\mu\text{A}$	BV_{ECO}	7			V
Collector emitter capacitance	$V_{CE} = 5\text{ V}$, $f = 1\text{ MHz}$	C_{CE}		2.8		pF
COUPLER						
Coupling capacitance	$f = 1\text{ MHz}$	C_{IO}		0.3		pF
Collector emitter saturation voltage	$I_F = 10\text{ mA}$, $I_C = 2.5\text{ mA}$	V_{CEsat}		0.12	0.4	V
Cut-off frequency	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 100\text{ }\Omega$	f_{ctr}		110		kHz

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$I_F = 5\text{ mA}$, $V_{CE} = 5\text{ V}$	VOM617A	CTR	50		600	%
		VOM617A-2	CTR	63		125	%
		VOM617A-3	CTR	100		200	%
		VOM617A-4	CTR	160		320	%
		VOM617A-6	CTR	250		500	%
		VOM617A-7	CTR	80		160	%
		VOM617A-8	CTR	130		260	%
		VOM617A-9	CTR	200		400	%

SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED						
Rise and fall time	$I_C = 2\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 100\text{ }\Omega$	t_r		3		μs
Fall time		t_f		3		μs
Turn-on time		t_{on}		6		μs
Turn-off time		t_{off}		4		μs
SATURATED						
Rise and fall time	$I_F = 1.6\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 1.9\text{ k}\Omega$	t_r		7		μs
Fall time		t_f		12		μs
Turn-on time		t_{on}		9		μs
Turn-off time		t_{off}		15		μs

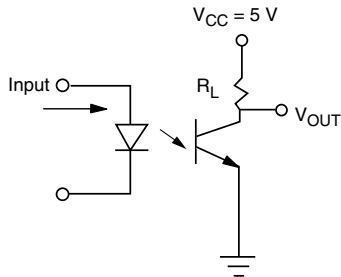


Fig. 2 - Test Circuit

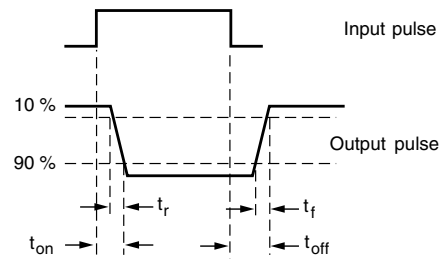


Fig. 3 - Test Circuit and Waveforms

SAFETY AND INSULATION RATINGS			
PARAMETER	SYMBOL	VALUE	UNIT
MAXIMUM SAFETY RATINGS			
Output safety power	P_{SO}	300	mW
Input safety current	I_{si}	200	mW
Safety temperature	T_S	150	°C
Comparative tracking index	CTI	175	
INSULATION RATED PARAMETERS			
Maximum withstanding isolation voltage	V_{ISO}	3750	V_{RMS}
Maximum transient isolation voltage	V_{IOTM}	6000	V_{peak}
Maximum repetitive peak isolation voltage	V_{IORM}	565	V_{peak}
Insulation resistance	$T_{amb} = 25\text{ °C}, V_{DC} = 500\text{ V}$	R_{IO}	10^{12} Ω
Insulation resistance	$T_{amb} = 100\text{ °C}, V_{DC} = 500\text{ V}$	R_{IO}	10^{11} Ω
Climatic classification (according to IEC 68 part 1)			55/110/21
Environment (pollution degree in accordance to DIN VDE 0109)			2
Internal creepage			≥ 5 mm
External creepage			≥ 5 mm
Clearance			≥ 5 mm
Insulation thickness			≥ 0.4 mm

Note

- As per DIN EN 60747-5-5 (VDE 0884), § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

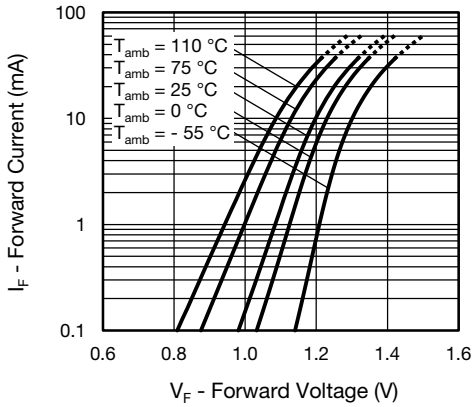


Fig. 4 - Forward Voltage vs. Forward Current

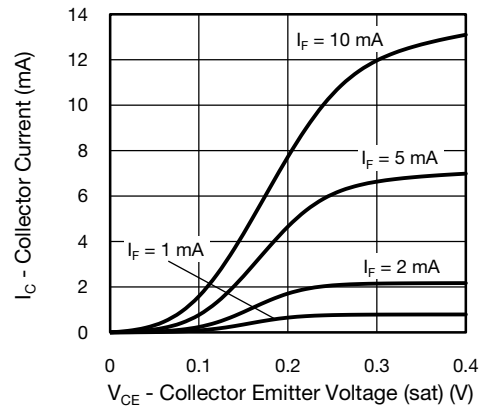


Fig. 7 - Collector Current vs. Collector Emitter Voltage (sat)

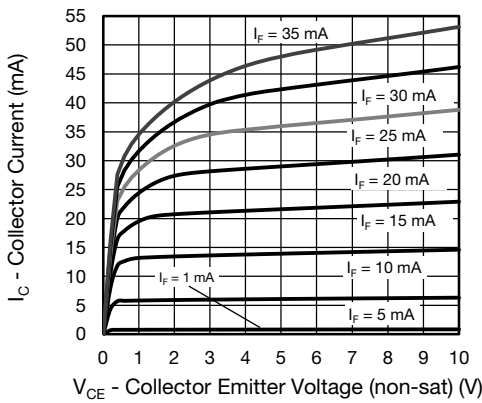


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

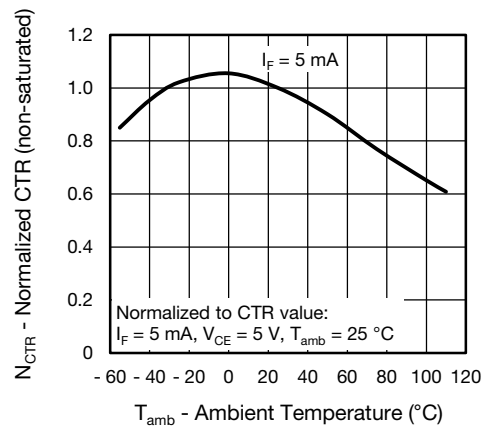


Fig. 8 - Normalized Current Transfer Ratio (non-sat) vs. Ambient Temperature

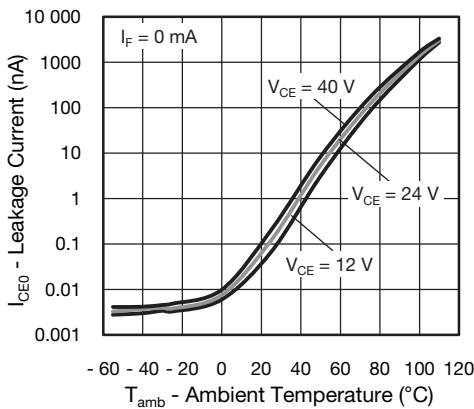


Fig. 6 - Leakage Current vs. Ambient Temperature

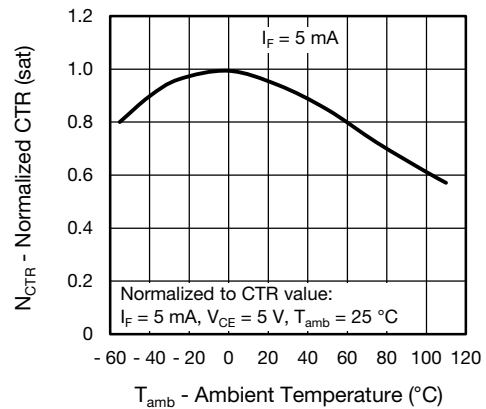


Fig. 9 - Normalized Current Transfer Ratio (sat) vs. Ambient Temperature

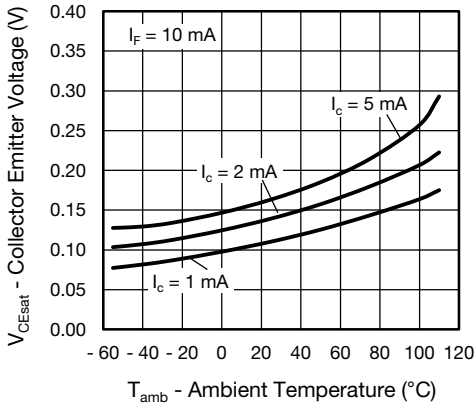


Fig. 10 - Collector Emitter Voltage vs. Ambient Temperature (saturated)

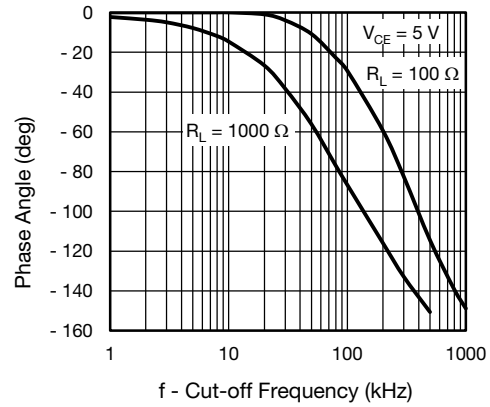


Fig. 13 - F_{CTR} vs. Phase Angle

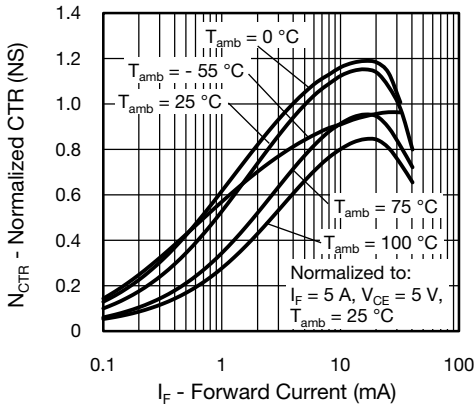


Fig. 11 - Normalized CTR (NS) vs. Forward Current

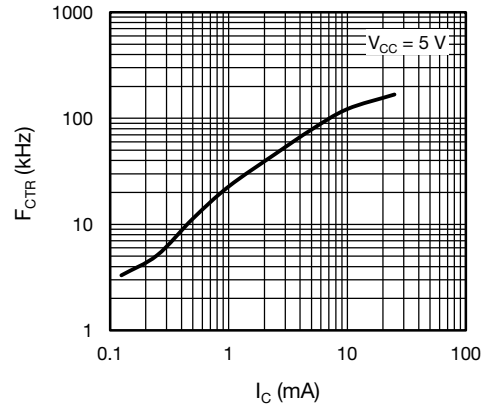


Fig. 14 - F_{CTR} vs. Collector Current

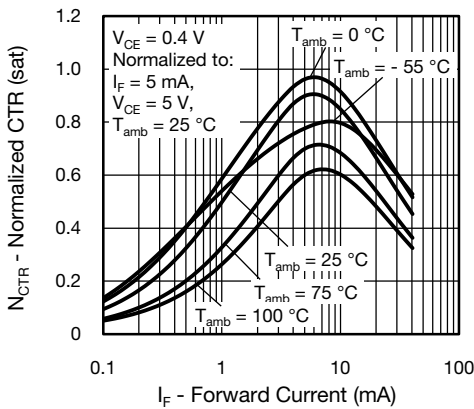


Fig. 12 - Normalized CTR (sat) vs. Forward Current

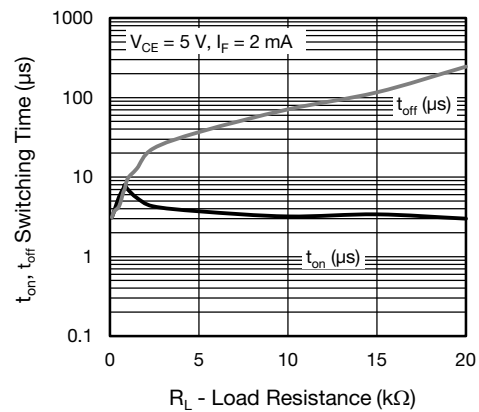
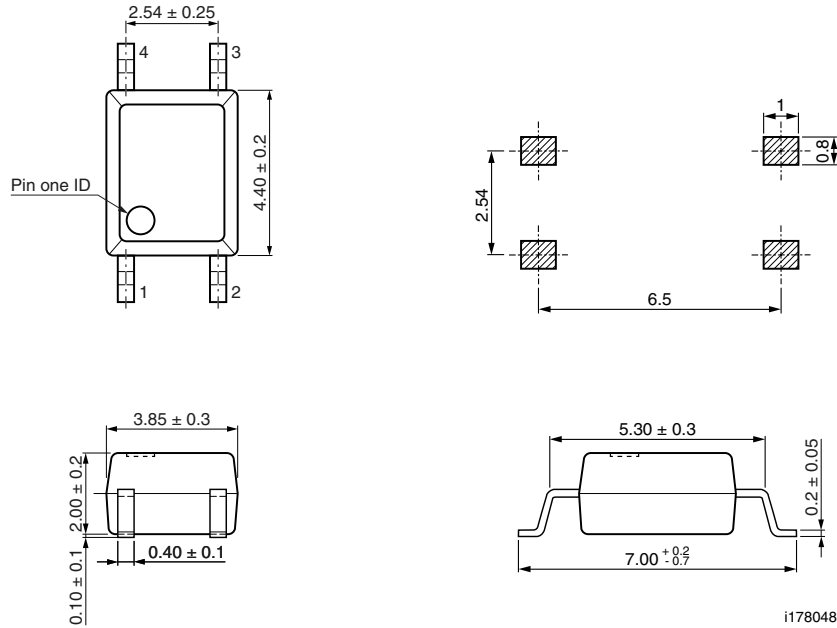


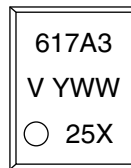
Fig. 15 - Switching Time vs. Load Resistance

PACKAGE DIMENSIONS in millimeters



i178048

PACKAGE MARKING (example of VOM617A-3X001T)



Notes

- Only option 1 is reflected in the package marking with the characters “X”.
- Tape and reel suffix (T) is not part of the package marking.

TAPE AND REEL DIMENSIONS in millimeters

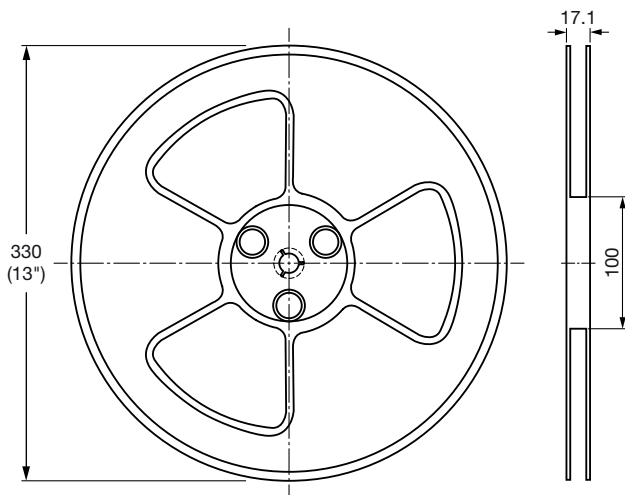


Fig. 16 - Reel Dimensions (3000 units per reel)

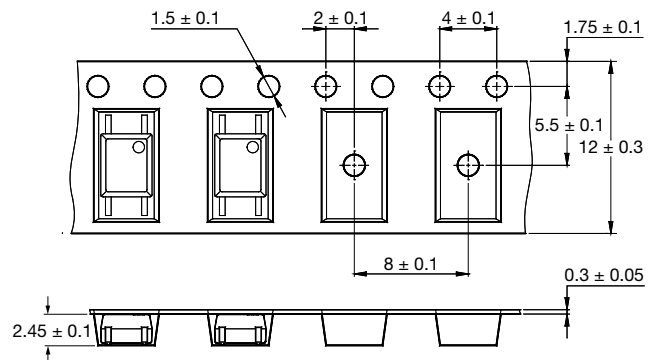


Fig. 17 - Tape Dimensions



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